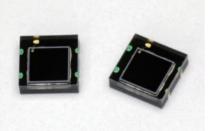


Si PIN photodiode



S12158-01CT

COB type, applicable to lead-free solder reflow

The S12158-01CT is a Si PIN photodiode for visible to near infrared range and is compatible with lead-free solder reflow processes. The small and thin leadless package allows reducing the mount area on a printed circuit board.

Features

- COB type, small and thin leadless package
- Applicable to lead-free solder reflow
- **▶** Photosensitive area: 2.77 × 2.77 mm
- ightharpoonup High sensitivity: 0.7 A/W (λ =960 nm)

Applications

- FSO (free space optics)
- Optical switches
- → Laser radar, etc.

Structure

Parameter	Specification	Unit
Photosensitive area	2.77 × 2.77	mm
Package	Glass epoxy	-
Seal material	Epoxy resin	-

■ Absolute maximum ratings

Parameter	Symbol	Condition	Value	Unit
Reverse voltage	VR max	Ta=25 °C	20	V
Operating temperature	Topr		-25 to +85	°C
Storage temperature	Tstg		-40 to +100	°C
Reflow soldering conditions*1	Tsol		Peak temperature 260 °C, 2 times (see page 4)	-

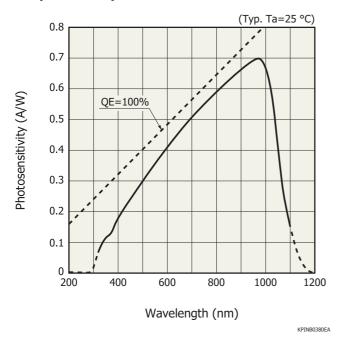
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

➡ Electrical and optical characterisitcs (Ta=25 °C)

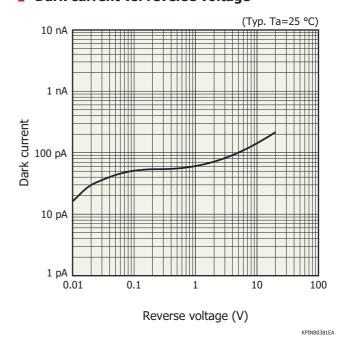
Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Spectral response range	λ		-	320 to 1100	-	nm
Peak sensitivity wavelength	λρ		-	960	-	nm
Photosensitivity	S	λ=λp	0.6	0.7	-	A/W
Dark current	ID	VR=12 V	-	0.1	10	nA
Temperature coefficient of ID	TCID	VR=12 V	-	1.15	-	times/°C
Cutoff frequency	fc	VR=12 V, RL=50 Ω -3 dB	10	25	-	MHz
Terminal capacitance	Ct	VR=12 V, f=1 MHz	-	15	30	pF

^{*1:} JEDEC level 4

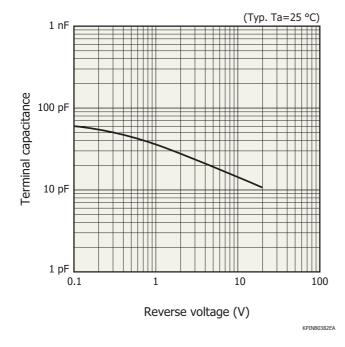
- Spectral response



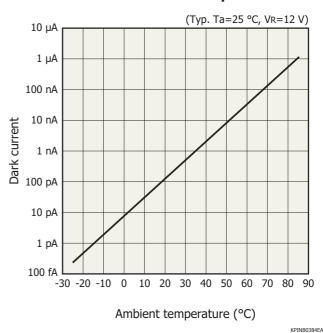
- Dark current vs. reverse voltage



Terminal capacitance vs. reverse voltage

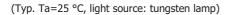


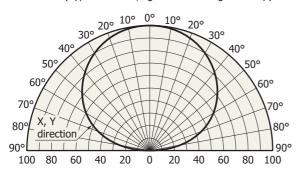
▶ Dark current vs. ambient temperature

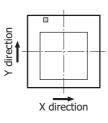


S12158-01CT

Directivity



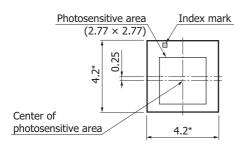


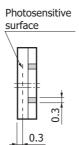


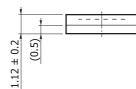
Relative sensitivity (%)

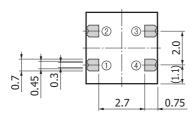
KPINB0383EA

Dimensional outline (unit: mm)









- ①② Anode (common)
- 34 Cathode (common)

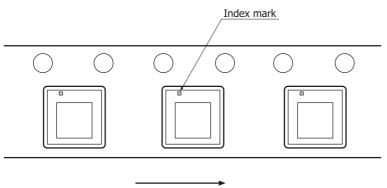
Tolerance unless otherwise

noted: ±0.1, ±2°

Chip position accuracy with respect to package dimensions marked* $X, Y \le \pm 0.2, \theta \le \pm 2^{\circ}$

Standard packing state: reel (2000 pcs/reel)

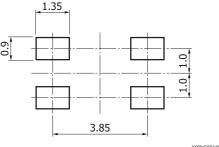
Product orientation on reel



Reel feed direction

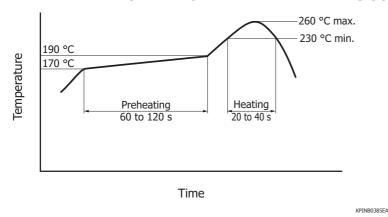


Recommended land pattern (unit: mm)



KPINC0019EA

- Recommended temperature profile of reflow soldering (typical example)



- · After unpacking, store this device in an environment at a temperature of 5 to 30 °C and a humidity below 70%, and perform reflow soldering on this device within 72 hours.
- The effect that the product receives during reflow soldering varies depending on the circuit board and reflow oven that are used. Before actual cleaning, check for any problems by testing out the cleaning methods in advance. A sudden temperature rise and cooling may be the cause of trouble, so make sure that the temperature change is within 4 °C per second.

Information described in this material is current as of October, 2012.

Product specifications are subject to change without prior notice due to improvements or other reasons. Before assembly into final products, please contact us for the delivery specification sheet to check the latest information.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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